REFERENCE	DESIGN	NOITA	IJ.S.	PATENT DOCUMENTS			
EXAMINER		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING IF APPROPRIATE
PAU	AA	5,045,498	9/3/91	WANG ET AL.	437	129	
PAC	AB				 		
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	AJ			<u></u>		<u> </u>	

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-	+	AK	517440	12/9/92	EP	H01S 3	06	
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	AP	Patent Abstract of Japan Publication No. 01074783. Publication Date: 3/20/89. Inventor: Ogita Shoichi "Semiconductor Light-Emitting Device."
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EXAMINER: Louglas Will DATE CONSIDERED: 35 Or

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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; * Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.